TOSHIBA Field Effect Transistor Silicon P Channel MOS Type (U-MOSⅢ)

TPC8112

Lithium Ion Battery Applications
Notebook PC Applications
Portable Equipment Applications

- Small footprint due to small and thin package
- Low drain-source ON resistance: $RDS(ON) = 5.0m\Omega(typ.)$
- High forward transfer admittance: $|Y_{fs}| = 31 \text{ S (typ.)}$
- Low leakage current: $IDSS = -10 \mu A (max) (VDS = -30 V)$
- Enhancement-mode: $V_{th} = -0.8 \text{ to } -2.0 \text{ V } (V_{DS} = -10 \text{ V}, I_D = -1 \text{ mA})$

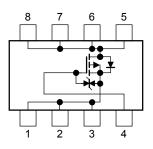
Unit: mm 8 8 5 6 7 8 SOURCE 4 GATE 5, 6, 7, 8 DRAIN JEDEC — JEITA — TOSHIBA 2-6J1B

Weight: 0.080 g (typ.)

Absolute Maximum Ratings (Ta = 25°C)

Characteris	stics	Symbol	Rating	Unit
Drain-source voltage		V _{DSS}	-30	X
Drain-gate voltage (Ro	$_{\rm SS} = 20 \text{ k}\Omega$)	$V_{ m DGR}$	-30	V
Gate-source voltage		VGSS	±20	\ \ \
Drain current	DC (Note 1)	GT.	-13	A
Diaili cuiteili	Pulse (Note 1)	/lpp	-52	
Drain power dissipation	n (t = 10 s) (Note 2a)	PD	1.9	W
Drain power dissipation	n (t = 10 s) (Note 2b)	PD	1.0	W
Single pulse avalanche	e energy (Note 3)	EAS	219	mJ
Avalanche current		I _{AR}	-13	Α
Repetitive avalanche e	energy ote 2a) (Note 4)	EAR	0.19	mJ
Channel temperature	<i>//</i>	Tch	150	°C
Storage temperature ra	ange	T _{stg}	-55 to 150	°C

Circuit Configuration



Note: (Note 1), (Note 2), (Note 3) and (Note 4): See the next page.

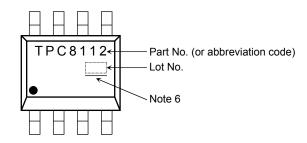
Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

This transistor is an electrostatic-sensitive device. Please handle with caution.

Thermal Characteristics

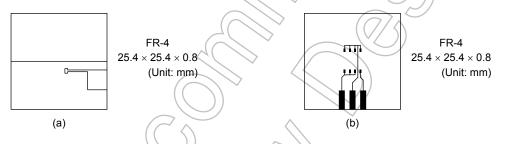
Characteristics	Symbol	Max	Unit
Thermal resistance, channel to ambient (t = 10 s) (Note 2a)	R _{th (ch-a)}	65.8	°C/W
Thermal resistance, channel to ambient (t = 10 s) (Note 2b)	R _{th (ch-a)}	125	°C/W

Marking (Note 5)



Note 1: Ensure that the channel temperature does not exceed 150°C.

Note 2: (a) Device mounted on a glass-epoxy board (b) Device mounted on a glass-epoxy board (b)



Note 3: $V_{DD} = 24 \text{ V}$, $T_{ch} = 25^{\circ}\text{C}$ (initial), L = 1.0 mH, $R_G = 25 \Omega$, $I_{AR} = -13 \text{ A}$

Note 4: Repetitive rating: pulse width limited by maximum channel temperature

Note 5: • on the lower left of the marking indicates Pin 1

* Weekly code: (Three digits)

Week of manufacture
(01 for first week of year, continuing up to 52 or 53)

Year of manufacture
(The last digit of the calendar year)

Note 6: A line under a Lot No. identifies the indication of product Labels.

Not underlined: [[Pb]]/INCLUDES > MCV

Underlined: [[G]]/RoHS COMPATIBLE or [[G]]/RoHS [[Pb]]

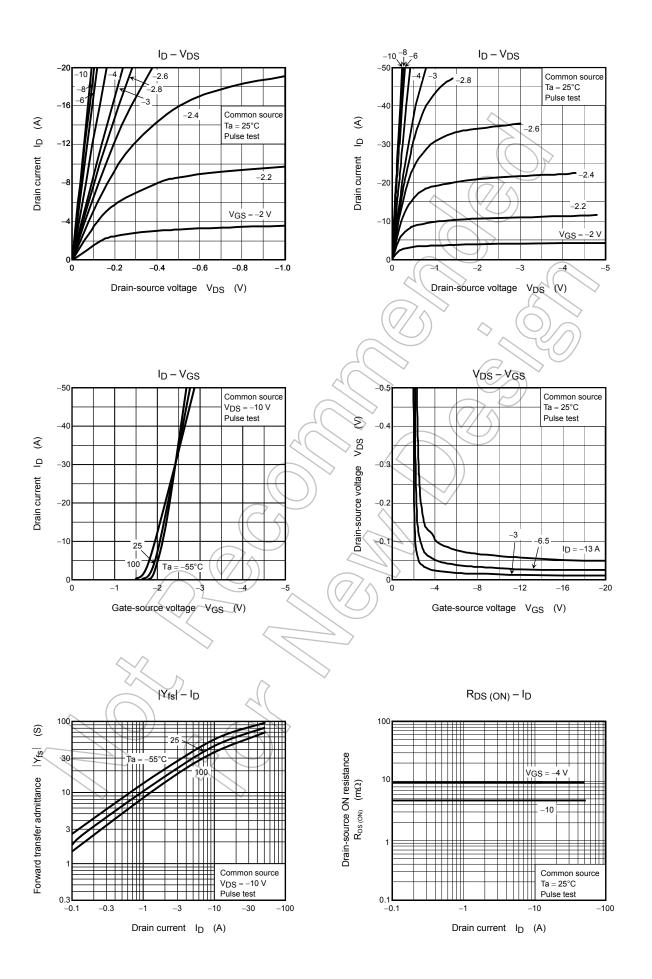
Please contact your TOSHIBA sales representative for details as to environmental matters such as the RoHS compatibility of Product. The RoHS is the Directive 2002/95/EC of the European Parliament and of the Council of 27 January 2003 on the restriction of the use of certain hazardous substances in electrical and electronic equipment.

Electrical Characteristics (Ta = 25°C)

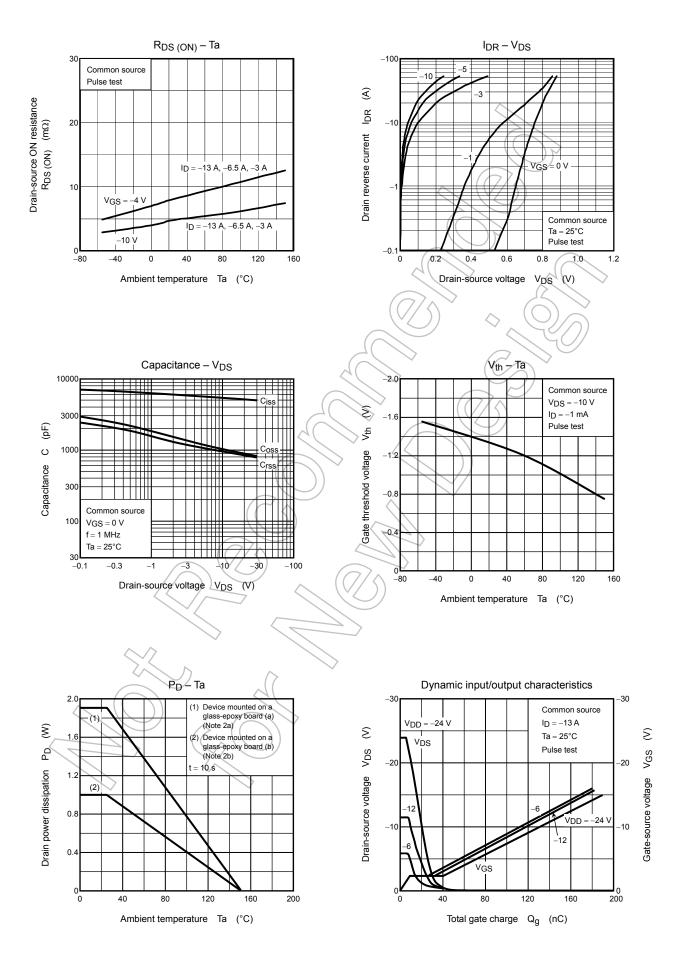
Char	acteristics	Symbol	Test Condition	Min	Тур.	Max	Unit	
Gate leakage curre	ent	I _{GSS}	$V_{GS} = \pm 16 \text{ V}, V_{DS} = 0 \text{ V}$	_	_	±10	μА	
Drain cut-OFF curr	ent	I _{DSS}	$V_{DS} = -30 \text{ V}, V_{GS} = 0 \text{ V}$	_	_	-10	μА	
Drain-source breakdown voltage		V (BR) DSS	$I_D = -10 \text{ mA}, V_{GS} = 0 \text{ V}$	-30	_	_	V	
Dialii-Source break	down voltage	V _{(BR) DSX}	$I_D = -10 \text{ mA}, V_{GS} = 20 \text{ V}$	-15	/	_	, v	
Gate threshold vol	tage	V _{th}	$V_{DS} = -10 \text{ V}, I_D = -1 \text{ mA}$	-0.8) /_	-2.0	V	
Drain-source ON resistance		D	$V_{GS} = -4 \text{ V}, I_D = -6.5 \text{ A}$) - -	9.0	14	- mΩ	
		R _{DS} (ON)	$V_{GS} = -10 \text{ V}, I_D = -6.5 \text{ A}$	\rightarrow	5.0	6.0		
Forward transfer a	dmittance	Y _{fs}	$V_{DS} = -10 \text{ V}, I_D = -6.5 \text{ A}$	15.5	31	_	S	
Input capacitance	Input capacitance			_	5880	_		
Reverse transfer capacitance		C _{rss}	$V_{DS} = -10 \text{ V}, V_{GS} = 0 \text{ V}, f = 1 \text{ MHz}$	_	1000	_	pF	
Output capacitance	Output capacitance				1050	\searrow		
	Rise time	t _r	V _{GS} -10 V I _D = -6.5 A V _{OUT} C C C C C C C C C	-(11	<u> </u>	- ns	
Switching time	Turn-ON time	t _{on}			22	_		
	Fall time	t _f			110	_		
	Turn-OFF time	t _{off}	V _{DD} ≃ -15 V Duty ≦ 1%, t _w = 10 μs) —	395	_		
Total gate charge (gate-source plus gate-drain)		Qg	$V_{DD} \simeq -24 \text{ V}, V_{GS} = 10 \text{ V},$	_	130	_	_	
Gate-source charge 1		Q _{gs1}	$I_D = -13 \text{ A}$		10		nC	
Gate-drain ("miller") charge		Q _{gd}		_	30	_		

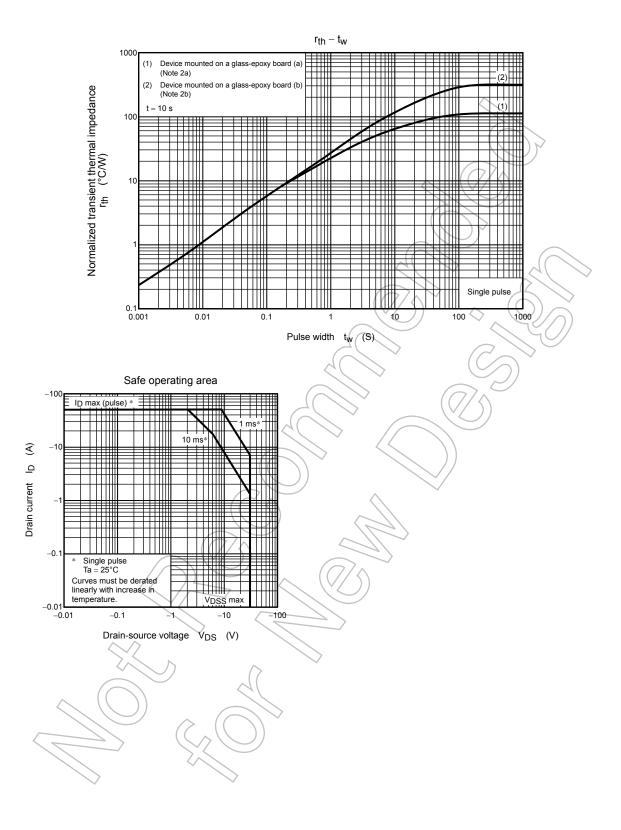
Source-Drain Ratings and Characteristics (Ta = 25°C)

Charac	eteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Drain reverse current	Pulse (Note 1)	I _{DRP}	_	_	_	-52	Α
Forward voltage (dio	de)	VDSF	$I_{DR} = -13 \text{ A}, V_{GS} = 0 \text{ V}$	_	_	1.2	V



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